Old Company Name in Catalogs and Other Documents

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April 1st, 2010 Renesas Electronics Corporation

Issued by: Renesas Electronics Corporation (http://www.renesas.com)

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HAT1054R

Silicon P Channel Power MOS FET High Speed Power Switching

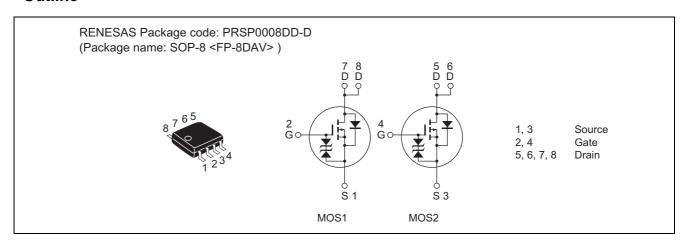
REJ03G1154-0300 (Previous: ADE-208-1224A)

Rev.3.00 Sep 07, 2005

Features

- Low on-resistance
- Capable of 2.5 V gate drive
- Low drive current
- High density mounting

Outline



Absolute Maximum Ratings

 $(Ta = 25^{\circ}C)$

Item	Symbol	Value	Unit
Drain to source voltage	V _{DSS}	-20	V
Gate to source voltage	V _{GSS}	±12	V
Drain current	I _D	-6	А
Drain peak current	I _{D (pulse)} Note 1	-48	Α
Body-drain diode reverse drain current	I _{DR}	-6	Α
Channel dissipation	Pch Note 2	2	W
Channel dissipation	Pch Note 3	3	W
Channel temperature	Tch	150	°C
Storage temperature	Tstg	-55 to +150	°C

Notes: 1. PW \leq 10 μ s, duty cycle \leq 1%

- 2. 1 Drive operation: When using the glass epoxy board (FR4 $40 \times 40 \times 1.6$ mm), PW ≤ 10 s
- 3. 2 Drive operation: When using the glass epoxy board (FR4 $40 \times 40 \times 1.6$ mm), PW ≤ 10 s

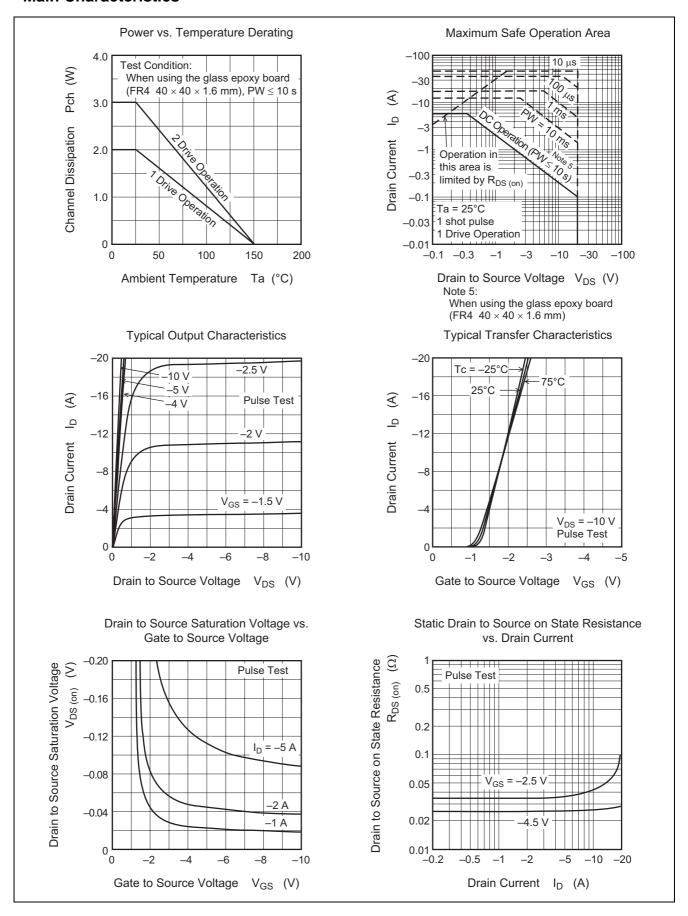
Electrical Characteristics

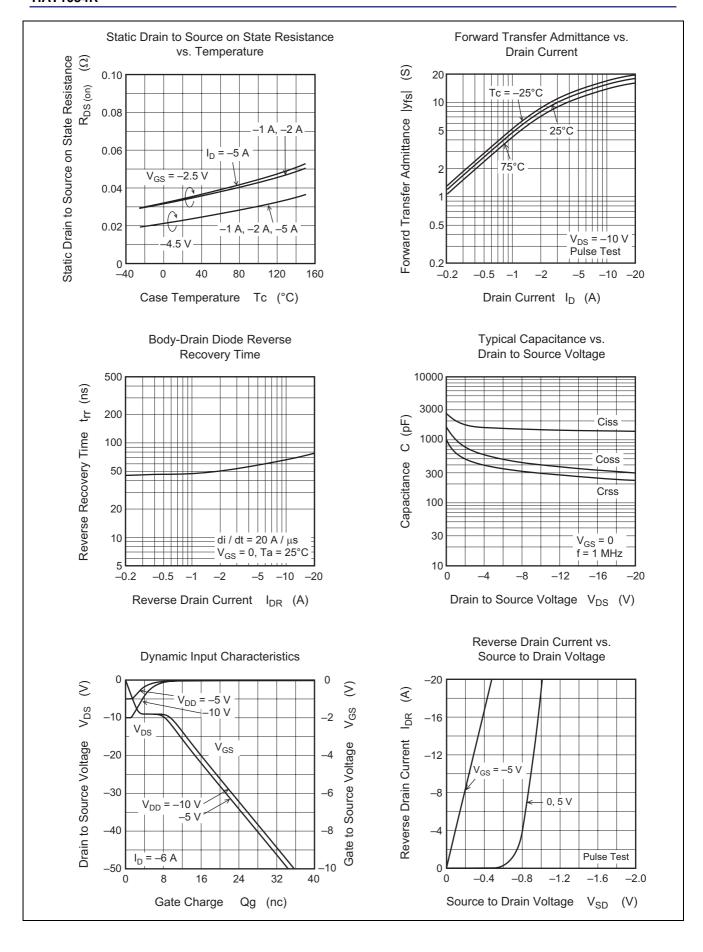
 $(Ta = 25^{\circ}C)$

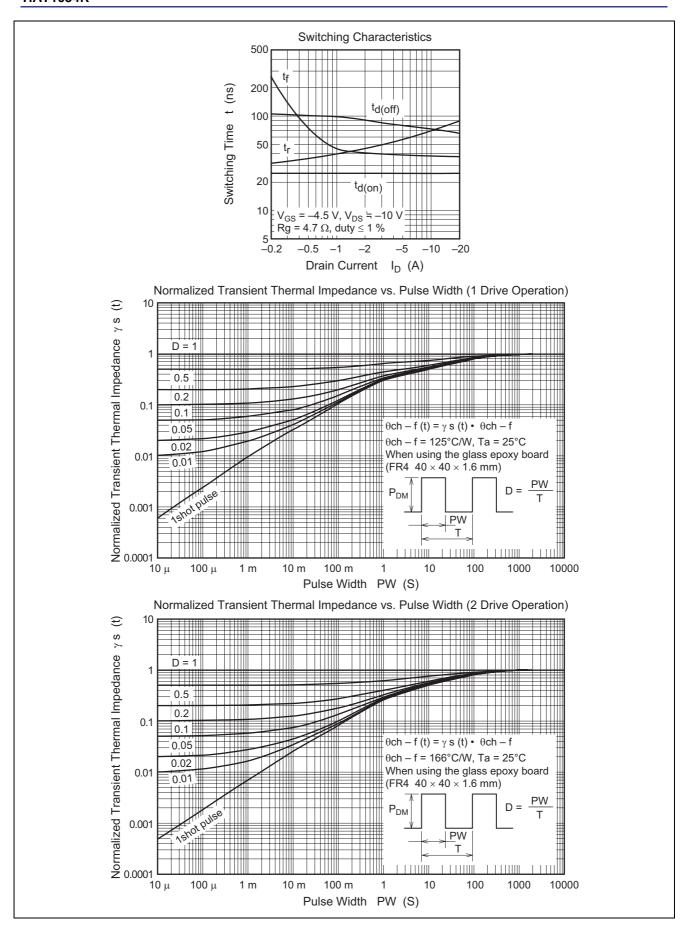
Item	Symbol	Min	Тур	Max	Unit	Test Conditions
Drain to source breakdown voltage	V _{(BR) DSS}	-20			V	$I_D = -10 \text{ mA}, V_{GS} = 0$
Gate to source breakdown voltage	V _{(BR) GSS}	±12	_	_	V	$I_G = \pm 100 \ \mu A, \ V_{DS} = 0$
Gate to source leak current	I _{GSS}	_	_	±10	μΑ	$V_{GS} = \pm 10 \text{ V}, V_{DS} = 0$
Zero gate voltage drain current	I _{DSS}	_	_	-1	μΑ	$V_{DS} = -20 \text{ V}, V_{GS} = 0$
Gate to source cutoff voltage	V _{GS (off)}	-0.4		-1.4	V	$V_{DS} = -10 \text{ V}, I_D = -1 \text{ mA}$
Static drain to source on state	R _{DS (on)}	_	24	30	mΩ	$I_D = -3 \text{ A}, V_{GS} = -4.5 \text{ V}^{\text{Note 4}}$
resistance	R _{DS (on)}	_	35	50	mΩ	$I_D = -3 \text{ A}, V_{GS} = -2.5 \text{ V}^{\text{Note 4}}$
Forward transfer admittance	y _{fs}	6	10	_	S	$I_D = -3 \text{ A}, V_{DS} = -10 \text{ V}^{\text{Note 4}}$
Input capacitance	Ciss	_	1550	_	pF	$V_{DS} = -10 \text{ V}$
Output capacitance	Coss	_	400	_	pF	$V_{GS} = 0$
Reverse transfer capacitance	Crss	_	300	_	рF	f = 1 MHz
Total gate charge	Qg	_	18	_	nC	$V_{DD} = -10 \text{ V}$
Gate to source charge	Qgs	_	3	_	nC	$V_{GS} = -4.5 \text{ V}$
Gate to drain charge	Qgd	_	6.5	_	nC	$I_D = -6 A$
Turn-on delay time	t _{d (on)}	_	25	_	ns	$V_{GS} = -4.5 \text{ V}, I_D = -3 \text{ A},$
Rise time	t _r	_	50	_	ns	$V_{DD}\cong -10 \text{ V}$
Turn-off delay time	t _{d (off)}	_	85	_	ns	$R_L = 3.3 \Omega$
Fall time	t _f	_	40	_	ns	$Rg = 4.7 \Omega$
Body-drain diode forward voltage	V_{DF}	_	-0.85	-1.10	V	$I_F = -6 \text{ A}, V_{GS} = 0^{\text{Note 4}}$
Body-drain diode reverse recovery time	t _{rr}	_	60	_	ns	$I_F = -6 \text{ A}, V_{GS} = 0$
						$di_F/dt = 20 A/\mu s$

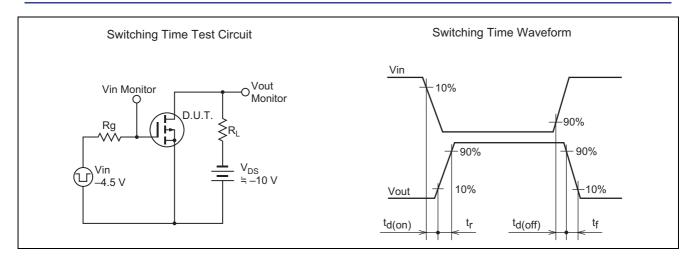
Note: 4. Pulse test

Main Characteristics

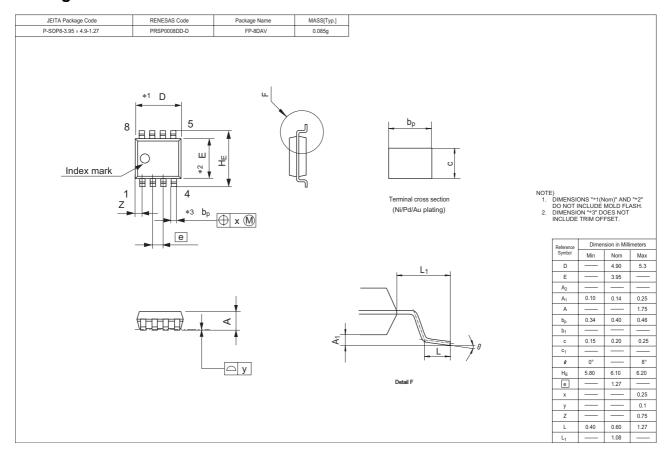








Package Dimensions



Ordering Information

Part Name	Quantity	Shipping Container
HAT1054R-EL-E	2500 pcs	Taping

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